20 V, 2 A NPN medium power transistors Rev. 8 — 18 October 2011

Product profile 1.

1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Product overview Table 1.

Type number ^[1]	Package	PNP complement		
	NXP	JEITA	JEDEC	
BCP68	SOT223	SC-73	-	BCP69
BC868	SOT89	SC-62	TO-243	BC869
BC68PA	SOT1061	-	-	BC69PA

[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Two current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 qualified

1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices

MOSFET drivers

Power management

Amplifiers

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	20	V
I _C	collector current		-	-	2	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	3	А



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Table 2.	Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h _{FE}	DC current gain	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<mark>[1]</mark> 85	-	375	
	h _{FE} selection -25	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<u>1</u> 160	-	375	

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
SOT223			
1	base		
2	collector		2, 4
3	emitter		1-
4	collector		3
SOT89			sym016
1	emitter		
2	collector		2 J
3	base		3
SOT1061			
1	base		2
2	emitter	3	3
3	collector		
		1 2 Transparent top view	sym021

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3. Ordering information

Table 4. Ordering information							
Type number ^[1]	Package	Package					
	Name	Description	Version				
BCP68	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223				
BC868	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89				
BC68PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061				

[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes	
Type number	Marking code
BCP68	BCP68
BCP68-25	BCP68/25
BC868	CAC
BC868-25	CDC
BC68PA	AR
BC68-25PA	AS

BCP68_BC868_BC68PA

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5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	32	V
V _{CEO}	collector-emitter voltage	open base	-	20	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	2	А
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	3	А
I _B	base current		-	0.4	А
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	0.4	A
P _{tot}	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$			
	BCP68		<u>[1]</u> -	0.65	W
			[2] _	1.00	W
			[3] _	1.35	W
	BC868		<u>[1]</u> _	0.50	W
			[2] _	0.95	W
			<u>[3]</u>	1.35	W
	BC68PA		<u>[1]</u> _	0.42	W
			[2] _	0.83	W
			<u>[3]</u> _	1.10	W
			<u>[4]</u> _	0.81	W
			<u>[5]</u> _	1.65	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

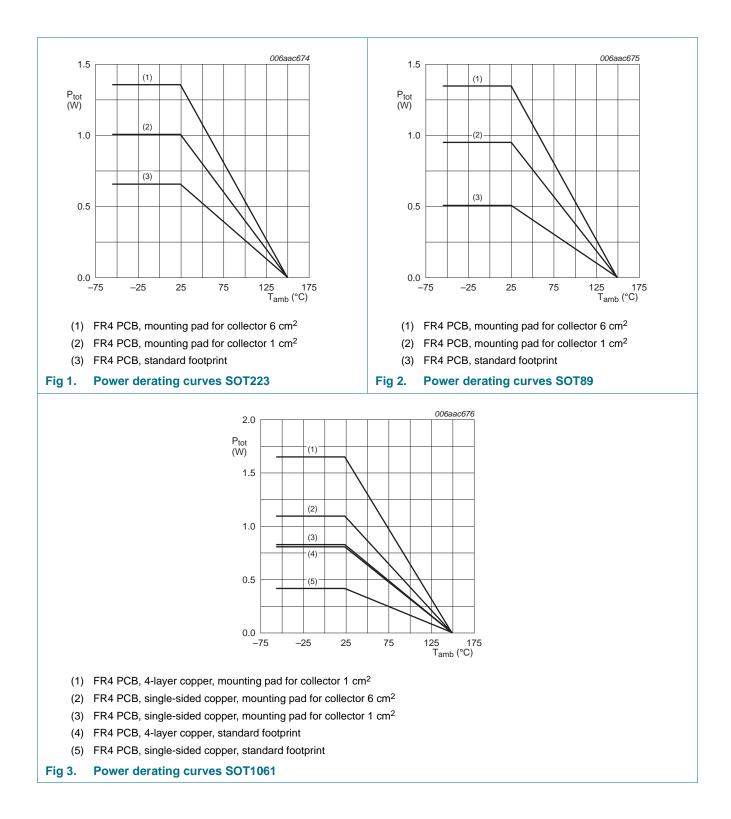
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



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6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
-				IVIIII	тур	IVIAX	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air					
	BCP68		<u>[1]</u>	-	-	192	K/W
			[2]	-	-	125	K/W
			[3]	-	-	93	K/W
	BC868		[1]	-	-	250	K/W
			[2]	-	-	132	K/W
			[3]	-	-	93	K/W
	BC68PA		[1]	-	-	298	K/W
			[2]	-	-	151	K/W
			[3]	-	-	114	K/W
			[4]	-	-	154	K/W
			[5]	-	-	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point						
	BCP68			-	-	16	K/W
	BC868			-	-	16	K/W
	BC68PA			-	-	20	K/W

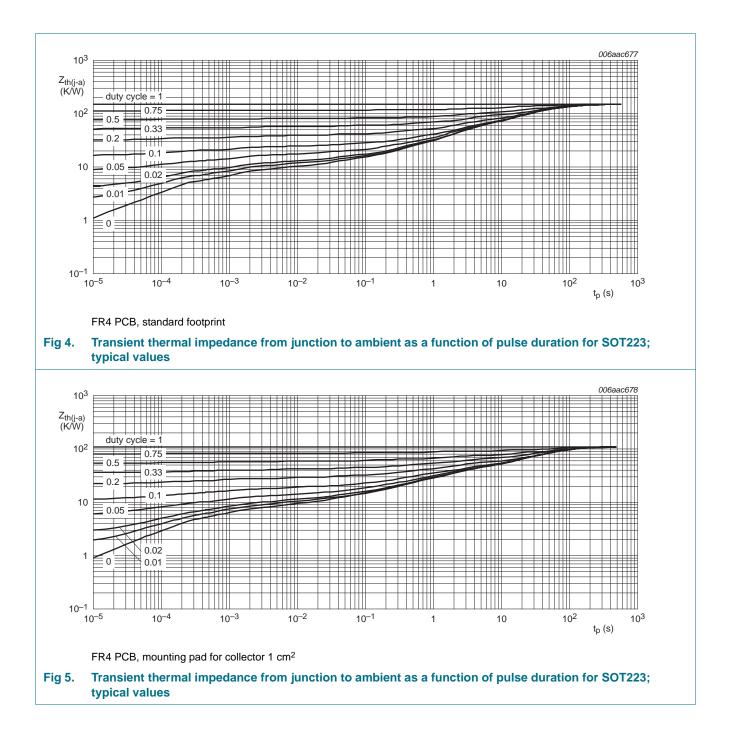
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

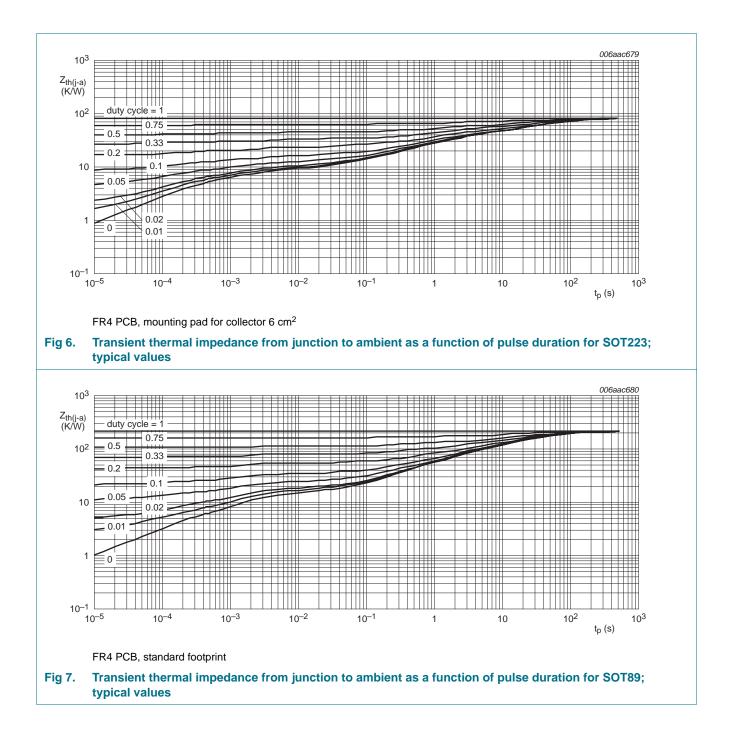
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

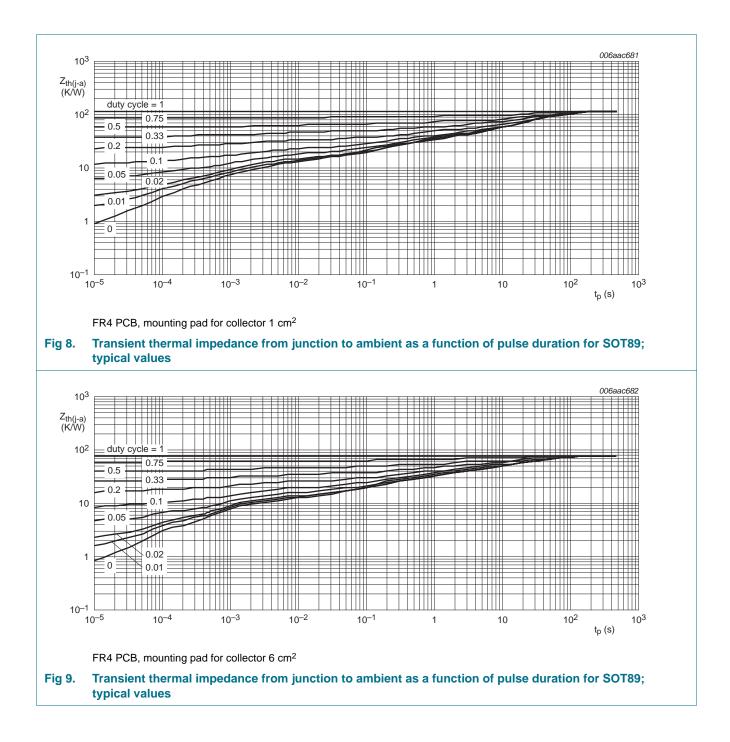
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

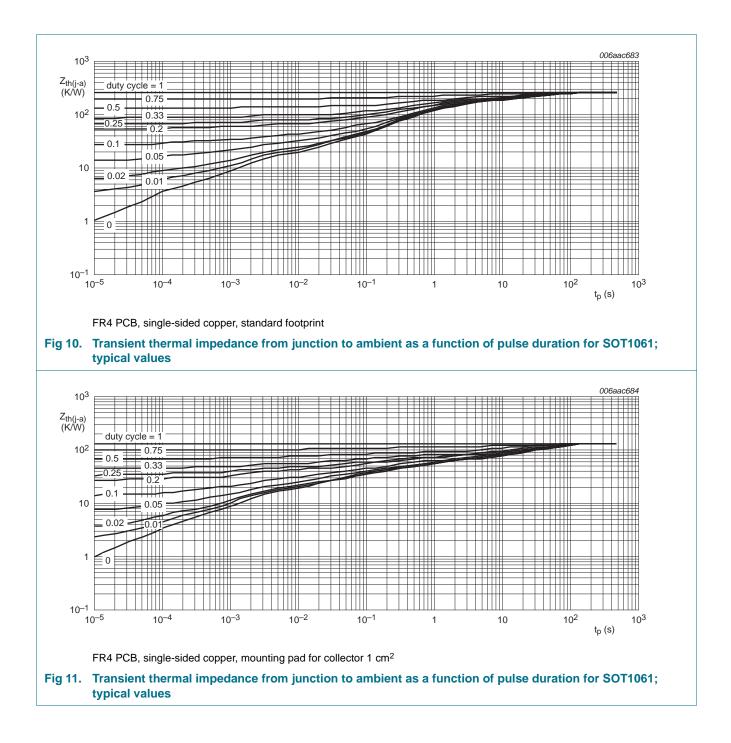
[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

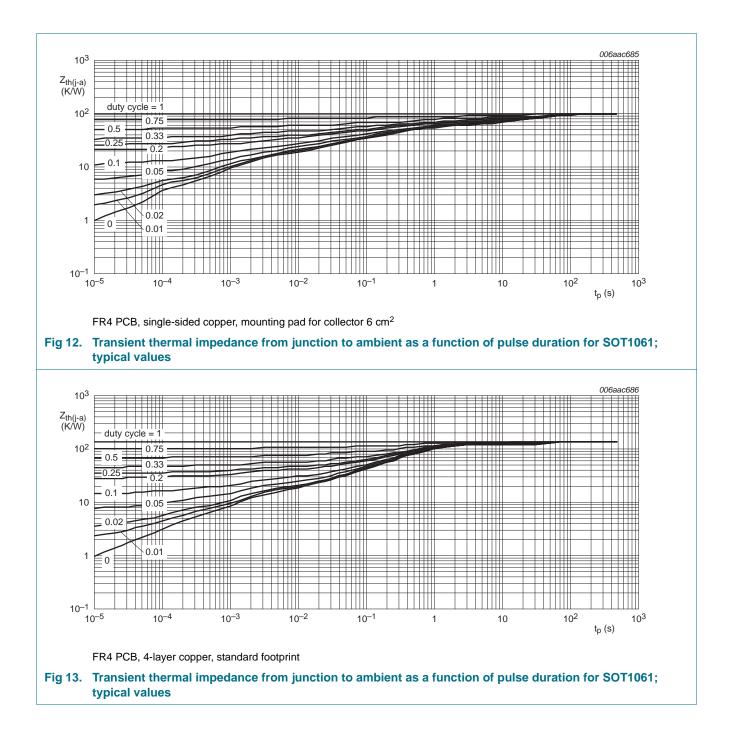
[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

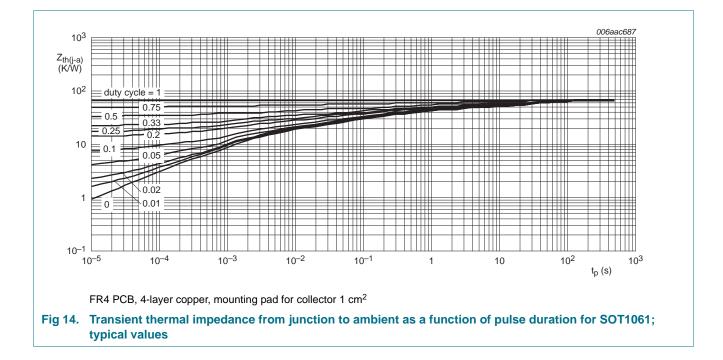










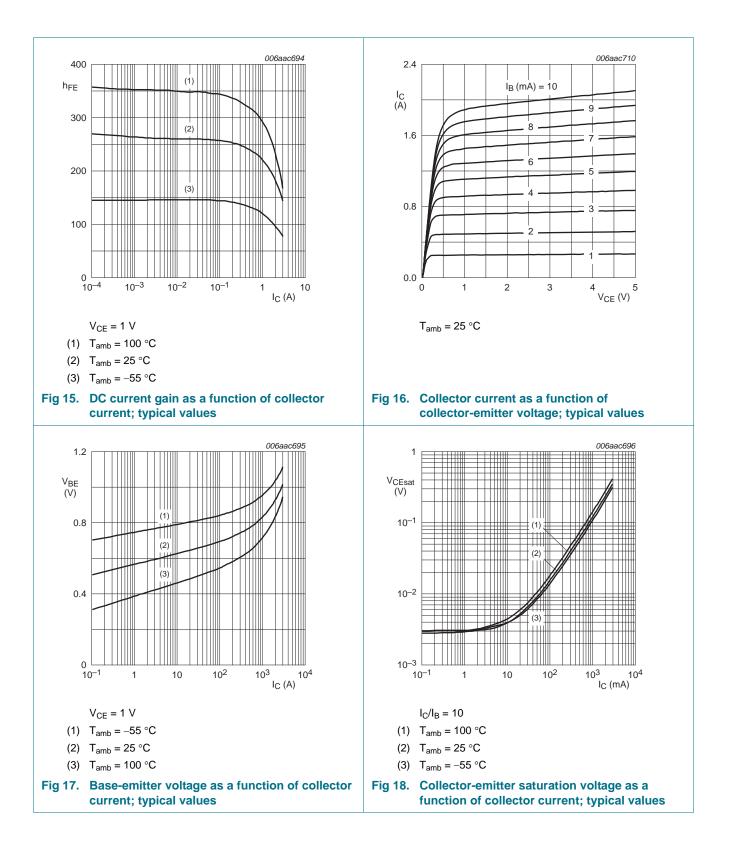


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7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	$V_{CB} = 25 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	100	nA
	current	$V_{CB} = 25 \text{ V}; \text{ I}_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 10 V					
		I _C = 5 mA		50	-	-	
	DC current gain	$V_{CE} = 1 V$					
		I _C = 500 mA	[1]	85	-	375	
		$I_{\rm C} = 1 \rm A$	[1]	60	-	-	
		I _C = 2 A	[1]	40	-	-	
	DC current gain	$V_{CE} = 1 V$					
	h _{FE} selection -25	I _C = 500 mA	[1]	160	-	375	
V _{CEsat}	collector-emitter	I _C = 1 A; I _B = 100 mA	[1]	-	-	0.5	V
	saturation voltage	$I_{C} = 2 \text{ A}; I_{B} = 200 \text{ mA}$	[1]	-	-	0.6	V
V _{BE}	base-emitter voltage	V_{CE} = 10 V; I_{C} = 5 mA	<u>[1]</u>	-	-	0.7	V
		$V_{CE} = 1 V; I_{C} = 1 A$	[1]	-	-	1	V
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	22	-	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz		40	170	-	MHz

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta = 0.02$.



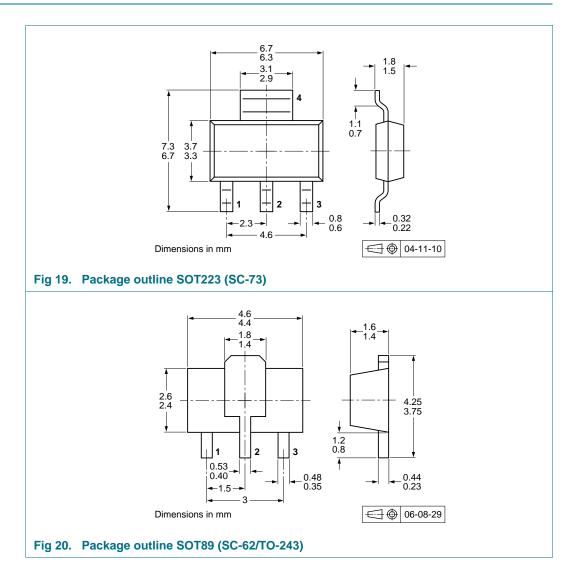
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8. Test information

8.1 Quality information

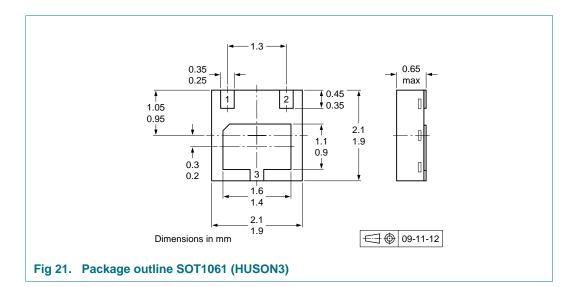
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



BCP68_BC868_BC68PA

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10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

BCP68 SOT223 8 mm pitch, 12 mm tape and reel -11513	Туре	Package	Description		Packin	ig quant	ity
BC868 SOT89 8 mm pitch, 12 mm tape and reel; T1 [3] -115 - -13 8 mm pitch, 12 mm tape and reel; T3 [4] -146 - -	number ^[2]				1000	3000	4000
8 mm pitch, 12 mm tape and reel; T3 [4] -146	BCP68	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
- · · · · · · · · · · · · · · · · · · ·	BC868	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
BC68PA SOT1061 4 mm pitch, 8 mm tape and reel115 -			8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
	BC68PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

[1] For further information and the availability of packing methods, see Section 14.

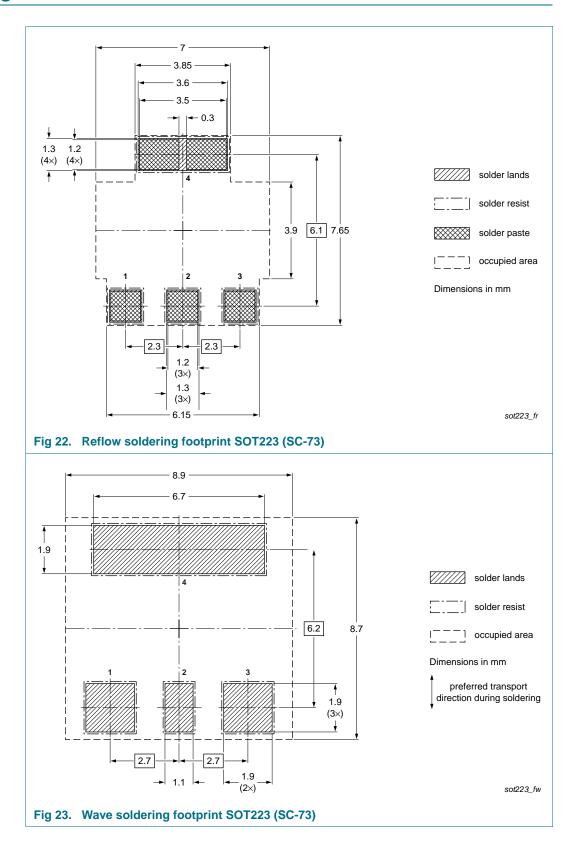
[2] Valid for all available selection groups.

[3] T1: normal taping

[4] T3: 90° rotated taping

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11. Soldering



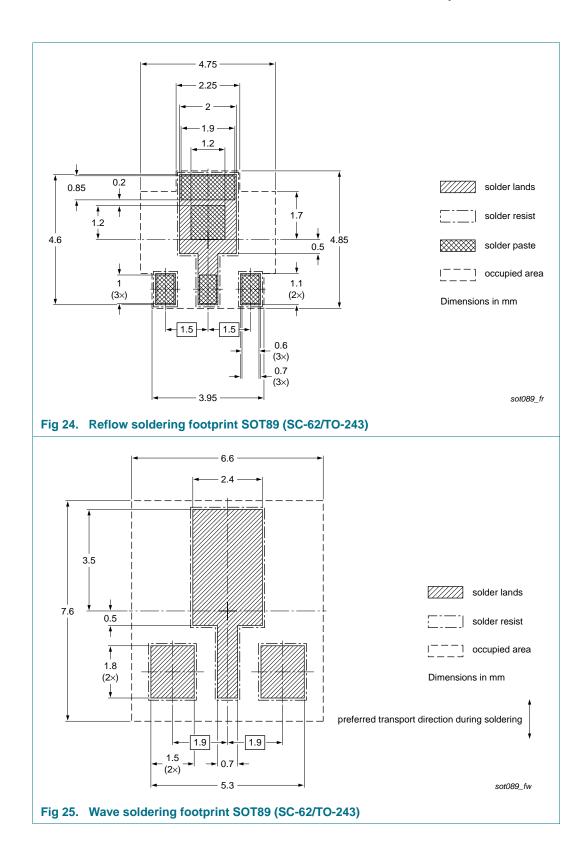
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Product data sheet

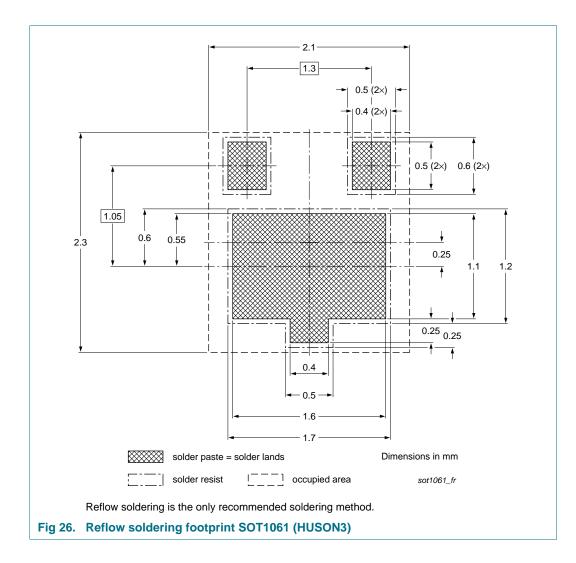
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12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCP68_BC868_BC68PA v.8	20111018	Product data sheet	-	BC868 v.7 BCP68 v.4		
Modifications:		of this document has be of NXP Semiconductors.	en redesigned to comp	bly with the new identity		
	 Legal texts 	have been adapted to th	e new company name	where appropriate.		
	 Type numb 	er BC68PA added				
	Section 1 "	Product profile": updated				
	Section 2 "	Pinning information": upd	ated			
	 Section 3 " 	Ordering information": up	dated			
	 Section 4 " 	Marking": updated				
	 Section 8 " 	Test information": added				
	 <u>Section 9 "Package outline"</u>: updated 					
	 <u>Section 10 "Packing information"</u>: added 					
	Section 11	"Soldering": added				
	• <u>Table 6, 7</u> a	and <u>8</u> : updated according	to latest measuremen	nts		
	 Figure 1, 2 	, <u>6</u> , <u>8</u> , <u>15</u> to <u>18</u> : updated				
	• Figure 3, 4	, <u>5</u> , <u>7</u> , <u>9</u> , <u>10</u> to <u>13</u> : added				
BC868 v.7	20041108	Product specification	-	BC868 v.6		
BC868 v.6	20031202	Product specification	-	BC868 v.5		
BC868 v.5	19990408	Product specification	-	BC868 v.4		
BC868 v.4	19980716	Product specification	-	BC868_CNV v.3		
BC868_CNV v.3	19970319	Product specification	-	BC868_CNV v.2		
BC868_CNV v.2	19970307	Product specification	-	-		
BCP68 v.4	20031125	Product specification	-	BCP68 v.3		
BCP68 v.3	19990408	Product specification	-	BCP68_CNV v.2		
BCP68_CNV v.2	19970409	Product specification				

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13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

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